

20 V, 3 A PNP low VCEsat transistor

21 June 2022

1. General description

PNP low V_{CEsat} transistor in in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4320T

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat} and corresponding low R_{CEsat}
- High collector current capability
- High collector current gain
- Improved efficiency due to reduced heat generation
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Power management applications
- Low and medium power DC/DC convertors
- Supply line switching
- Battery chargers
- Linear voltage regulation with low voltage drop-out (LDO).

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-20	V
I _C	collector current		-	-	-2	А
I _{CRM}		$\delta \le 0.25$; Operated under pulsed conditions; $t_p \le 100$ ms	-	-	-3	A
R _{CEsat}	collector-emitter saturation resistance	I _C = -2 A; I _B = -200 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	75	105	mΩ

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	E	emitter		С
3	С	collector		B E sym132

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PBSS5320T-Q		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	<u>SOT23</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS5320T-Q	ZH%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-20	V
V _{CEO}	collector-emitter voltage	open base		-	-20	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
l _C	collector current			-	-2	А
I _{CRM}	repetitive peak collector current	$\delta \le 0.25$; Operated under pulsed conditions; $t_p \le 100$ ms		-	-3	A
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-5	А
I _B	base current			-	-0.5	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
			[2]	-	480	mW
			[3]	-	540	mW
			[1] [4]	-	1.2	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C

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Symbol	Parameter	Conditions	Min	Max	Unit
T _{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm²

[4] Operated under pulsed conditions: pulse width $t_p \le 100$ ms; duty cycle $\delta \le 0.25$.

9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)} thermal resistance from junction to ambient		[1]	-	-	417	K/W	
		[2]	-	-	260	K/W	
		[3]	-	-	230	K/W	
			[1] [4]	-	-	104	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

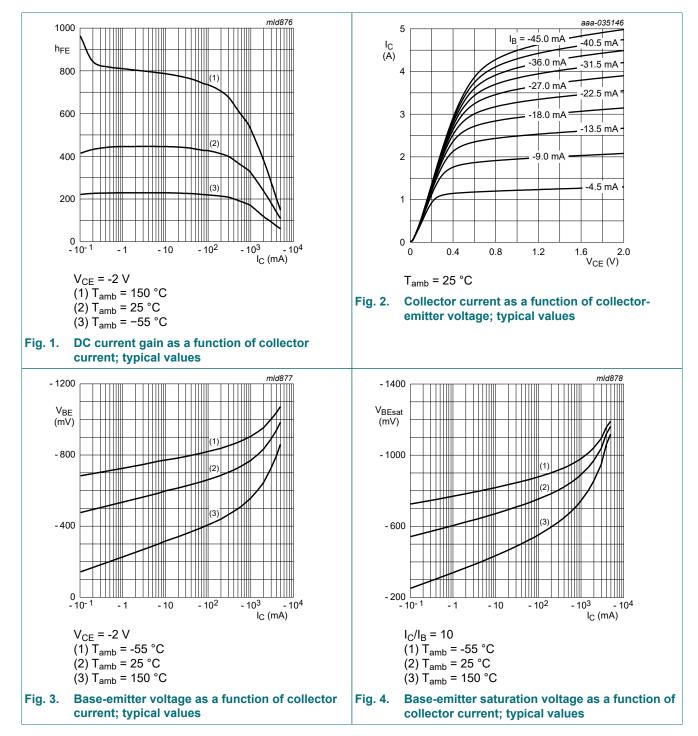
[4] Operated under pulsed conditions: pulse width $t_p \le 100$ ms; duty cycle $\delta \le 0.25$.

10. Characteristics

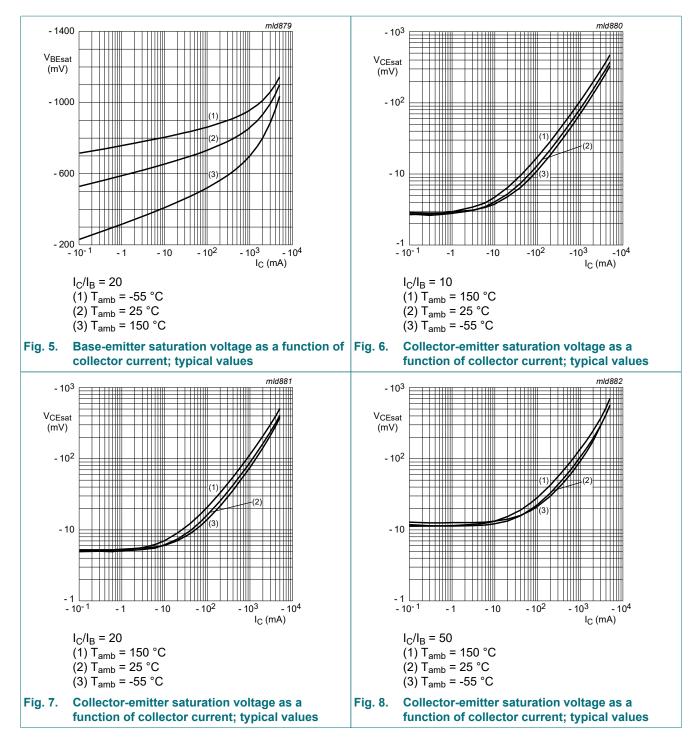
Table 7. Characteristics Conditions Unit Symbol Parameter Min Max Тур V_{CB} = -20 V; I_E = 0 A; T_{amb} = 25 °C collector-base cut-off -100 nA I_{CBO} current V_{CB} = -20 V; I_E = 0 A; T_i = 150 °C -50 uА V_{EB} = -5 V; I_C = 0 A; T_{amb} = 25 °C emitter-base cut-off -100 I_{EBO} _ nA current V_{CE} = -2 V; I_C = -100 mA; T_{amb} = 25 °C DC current gain 220 h_{FE} V_{CE} = -2 V; I_C = -500 mA; T_{amb} = 25 °C 220 V_{CE} = -2 V; I_C = -1 A; pulsed; t_p ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C 200 V_{CE} = -2 V; I_C = -2 A; pulsed; t_p ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C 150 V_{CE} = -2 V; I_C = -3 A; pulsed; $t_p \le$ 100 $300 \ \mu s; \delta ≤ 0.02; T_{amb} = 25 \ °C$ I_C = -500 mA; I_B = -50 mA; T_{amb} = 25 °C collector-emitter -70 mV VCEsat saturation voltage I_C = -1 A; I_B = -50 mA; T_{amb} = 25 °C -130 mV I_C = -2 A; I_B = -100 mA; pulsed; $t_p \le$ -230 mV 300 μs; $\delta \le 0.02$; T_{amb} = 25 °C $I_{\rm C}$ = -2 A; $I_{\rm B}$ = -200 mA; pulsed; $t_{\rm p} \leq$ -210 mV _ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C $I_{\rm C}$ = -3 A; $I_{\rm B}$ = -300 mA; pulsed; $t_{\rm p} \leq$ -300 mV 300 μs; δ ≤ 0.02; T_{amb} = 25 °C collector-emitter I_{C} = -2 A; I_{B} = -200 mA; pulsed; $t_{p} \leq$ 75 105 mΩ R_{CEsat} saturation resistance 300 μs; $\delta \le 0.02$; T_{amb} = 25 °C base-emitter saturation I_{C} = -2 A; I_{B} = -100 mA; pulsed; $t_{p} \leq$ -1.1 v **V**_{BEsat} 300 μs; δ ≤ 0.02; T_{amb} = 25 °C voltage I_{C} = -3 A; I_{B} = -300 mA; pulsed; $t_{p} \leq$ V -1.2 300 μs; δ ≤ 0.02; T_{amb} = 25 °C

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I _C = -1 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-1.2	-	-	V
f _T	transition frequency	V_{CE} = -5 V; I _C = -100 mA; f = 100 MHz; T _{amb} = 25 °C	100	-	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	50	pF

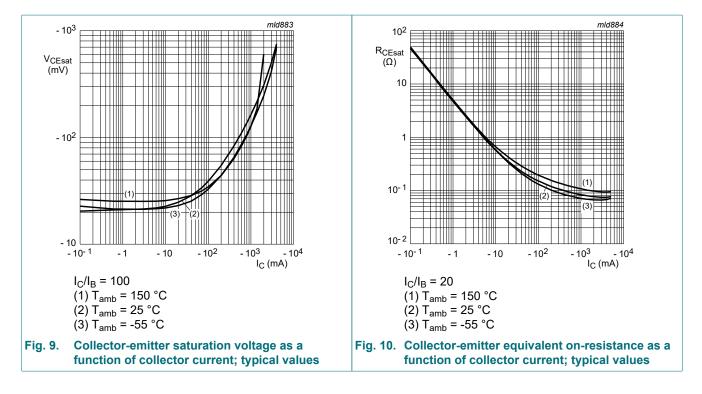


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Product data sheet

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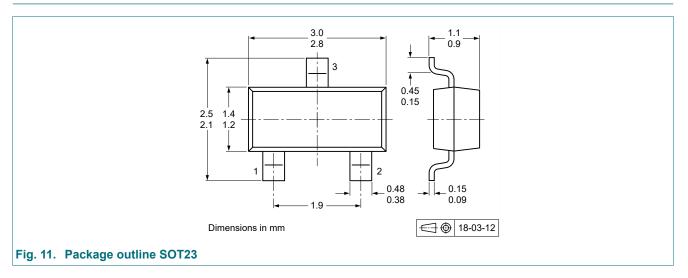


11. Test information

Quality information

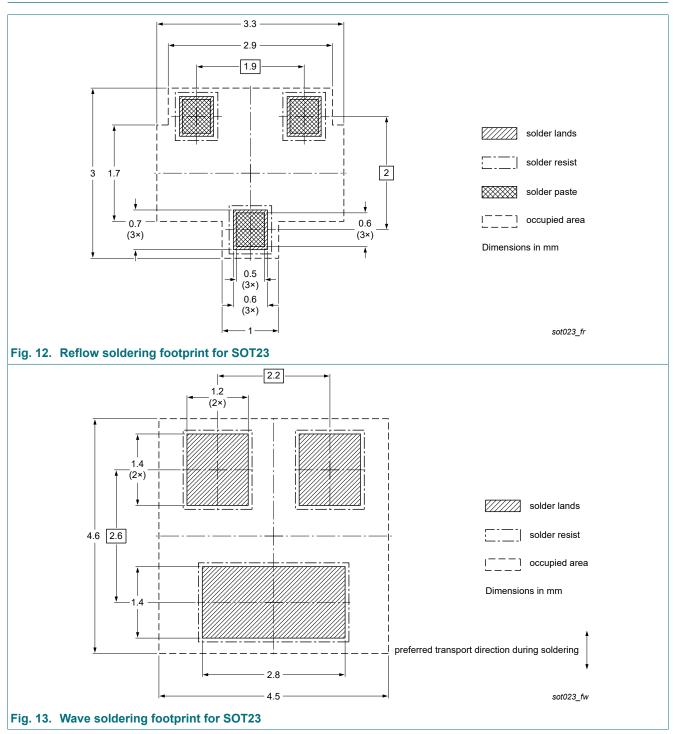
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS5320T-Q v.2	20220621	Product data sheet	-	PBSS5320T-Q v.1		
Modifications:	Characteristics: Figu	Characteristics: Figure 2 added				
PBSS5320T-Q v.1	20220505	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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